

2A, 600V N-CHANNEL MOSFET

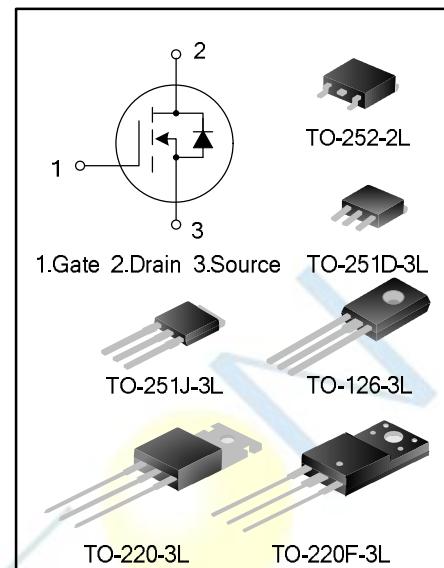
GENERAL DESCRIPTION

This power mosfet is an N-channel enhancement mode power MOS field effect transistor which is produced using Hi-semicon proprietary F-Cell™ structure VDMOS technology. The improved planar stripe cell and the improved guard ring terminal have been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode.

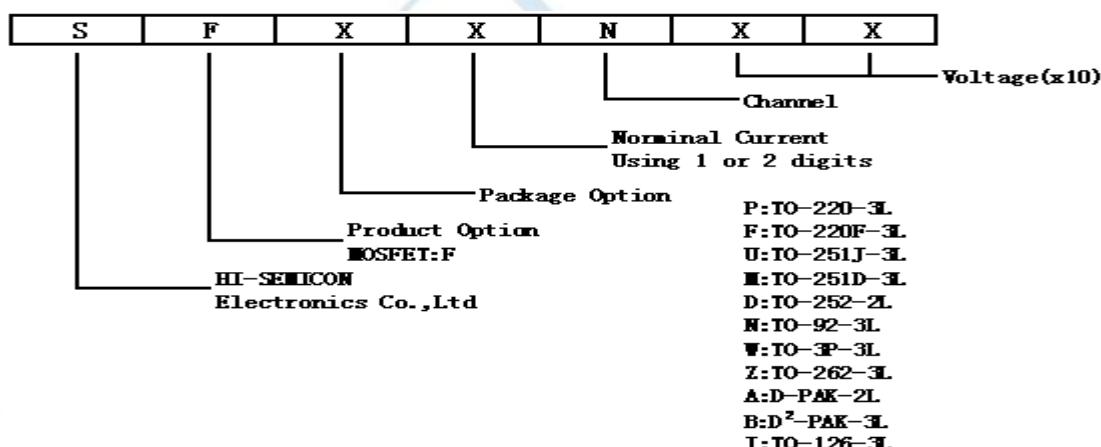
These devices are widely used in AC-DC power suppliers, DC-DC converters and H-bridge PWM motor drivers.

FEATURES

- ◆ 2A, 600V, $R_{DS(on)(typ.)} = 3.7\Omega$ @ $V_{GS} = 10V$
- ◆ Low gate charge
- ◆ Low Crss
- ◆ Fast switching
- ◆ Improved dv/dt capability



NOMENCLATURE



ORDERING INFORMATION

Part No.	Package Type	Marking	Material	Packing
SFM2N60	TO-251D-3L	SFM2N60	Pb free	Tube
SFU2N60	TO-251J-3L	SFU2N60	Pb free	Tube
SFI2N60	TO-126-3L	SFI2N60	Pb free	Bulk
SFF2N60	TO-220F-3L	SFF2N60	Pb free	Tube
SFP2N60	TO-220-3L	SFP2N60	Pb free	Tube
SFD2N60	TO-252-2L	SFD2N60	Pb free	Tape & Reel

SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS

Characteristics	Symbol	Test conditions	Min.	Typ.	Max.	Unit
Continuous Source Current	I_S	Integral Reverse P-N Junction Diode in the MOSFET	--	--	2.0	A
Pulsed Source Current	I_{SM}		--	--	8.0	
Diode Forward Voltage	V_{SD}	$I_S=2.0A, V_{GS}=0V$	--	--	1.4	V
Reverse Recovery Time	T_{rr}	$I_S=2.0A, V_{GS}=0V,$ $dI_F/dt=100A/\mu S$	--	356.75	--	ns
Reverse Recovery Charge	Q_{rr}	--	--	1.03	--	μC

Notes:

1. $L=30mH, I_{AS}=2.52, V_{DD}=145V, R_G=25\Omega$, starting $T_J=25^\circ C$;
2. Pulse Test: Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$;
3. Essentially independent of operating temperature.

TYPICAL CHARACTERISTICS

Figure 1. On-Region Characteristics

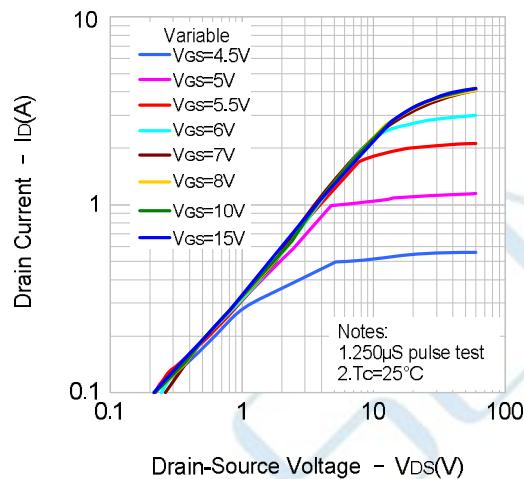


Figure 2. Transfer Characteristics

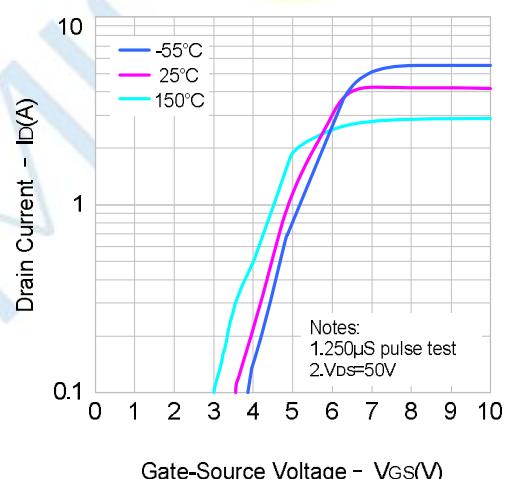


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

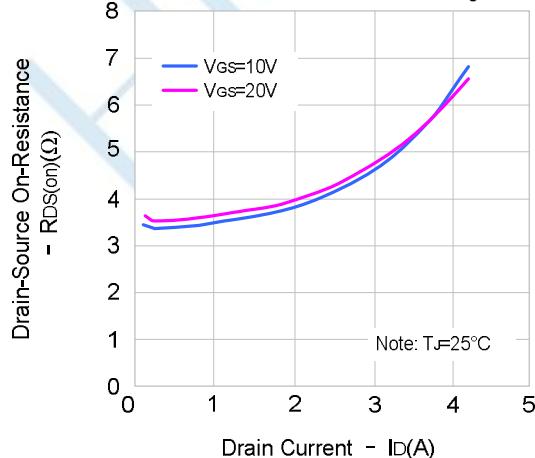
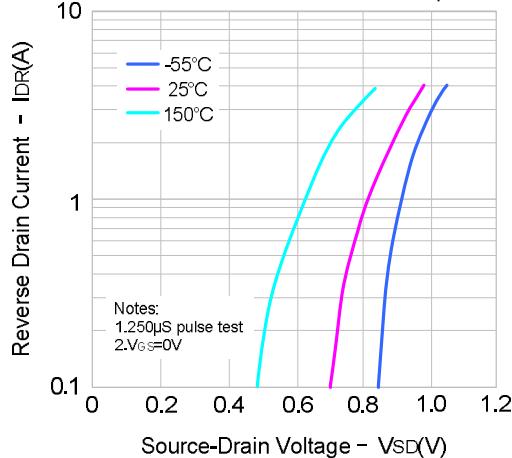


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature



TYPICAL CHARACTERISTICS(CONTINUED)

Figure 5. Capacitance Characteristics

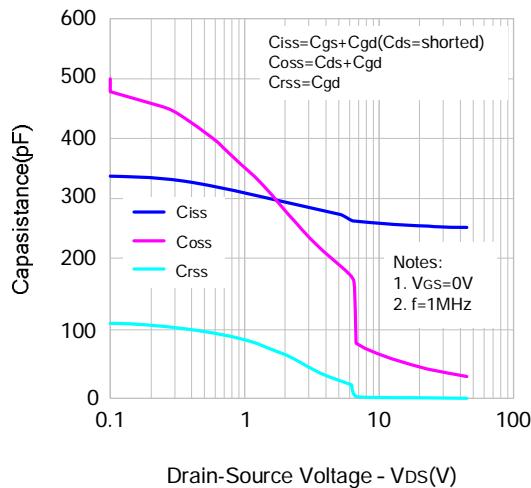


Figure 6. Gate Charge Characteristics

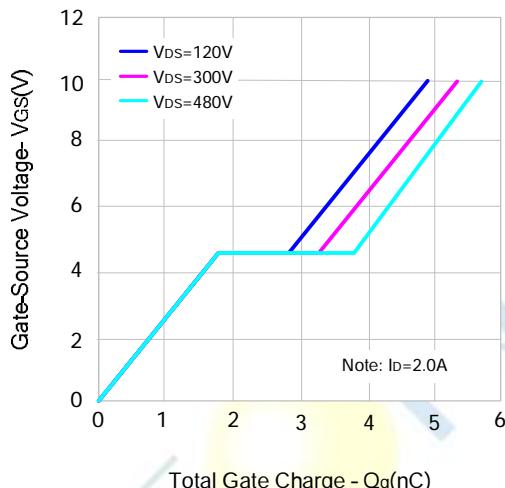


Figure 7. Breakdown Voltage Variation vs. Temperature

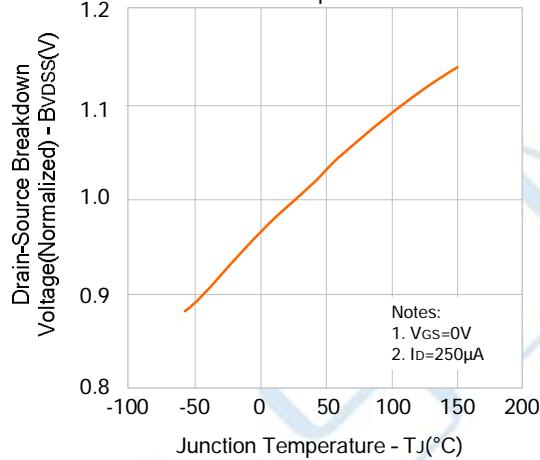


Figure 8. On-resistance Variation vs. Temperature

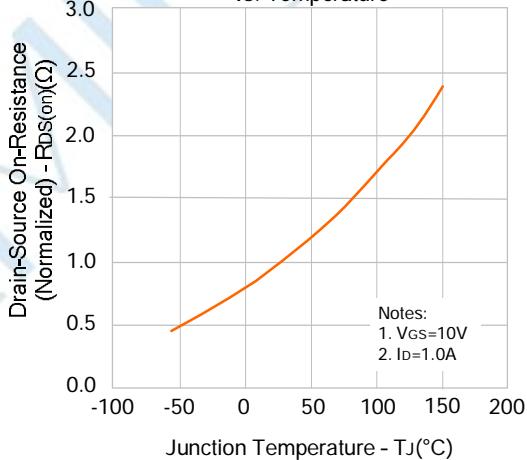


Figure 9-1. Max. Safe Operating Area (SFD/M2N60)

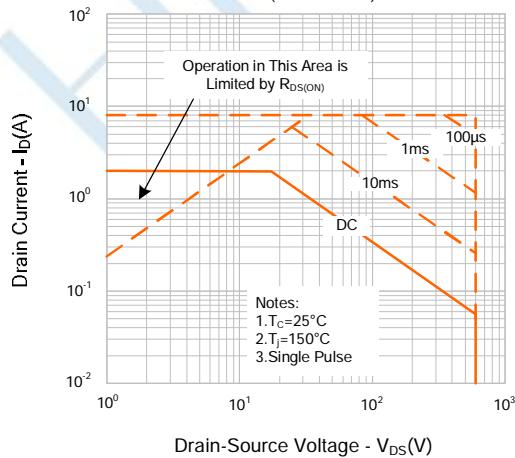
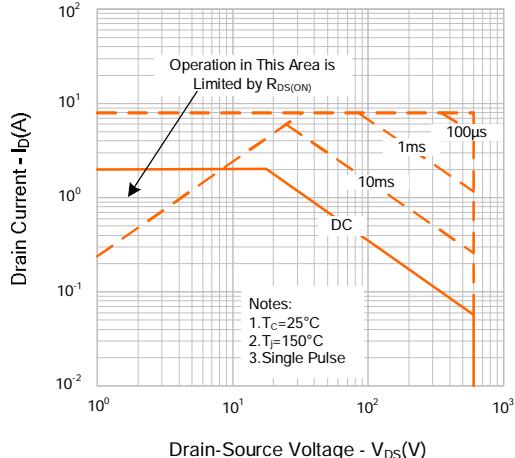


Figure 9-2. Max. Safe Operating Area (SFU2N60)



TYPICAL CHARACTERISTICS (CONTINUED)

Figure 9-3. Max. Safe Operating Area (SFP2N60)

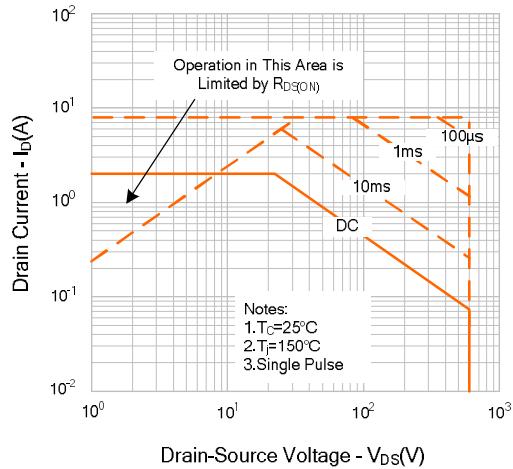


Figure 9-4. Max. Safe Operating Area (SFF2N60)

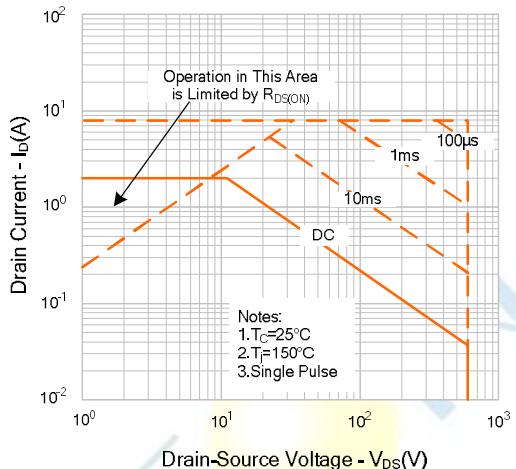


Figure 9-5. Max. Safe Operating Area (SFI2N60)

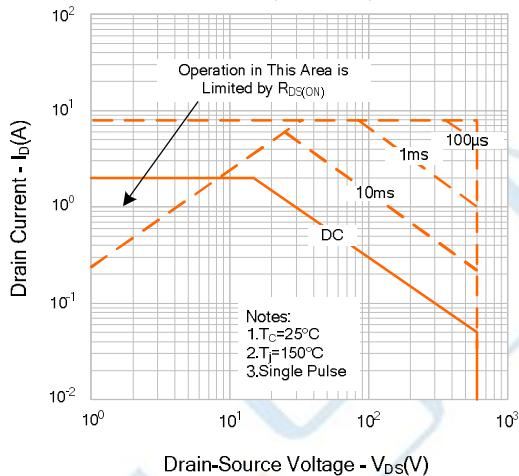
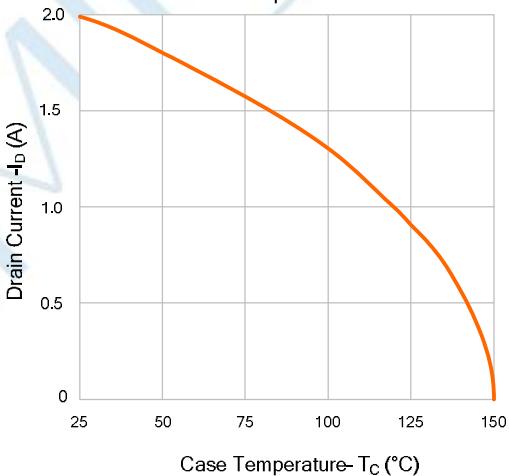
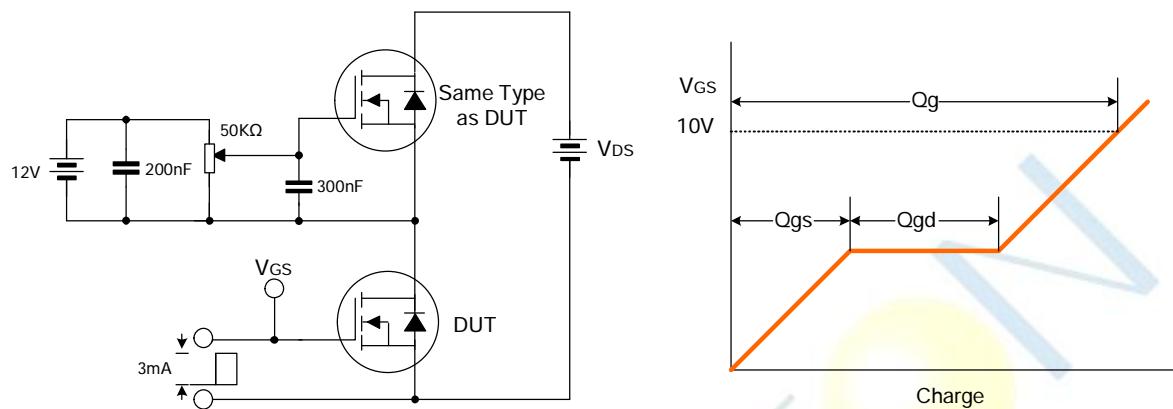


Figure 10. Max. Drain Current vs. Case Temperature

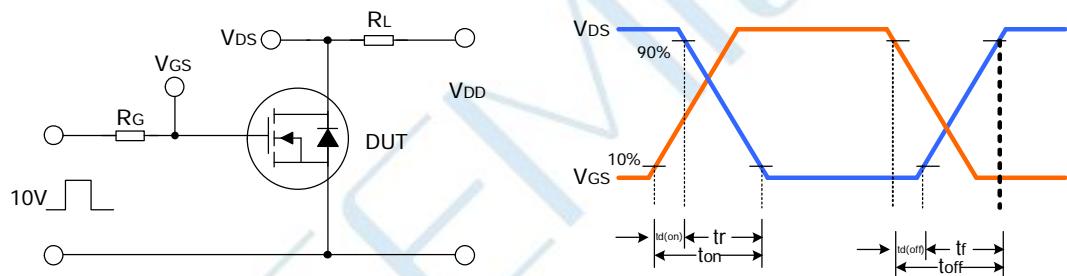


TYPICAL TEST CIRCUIT

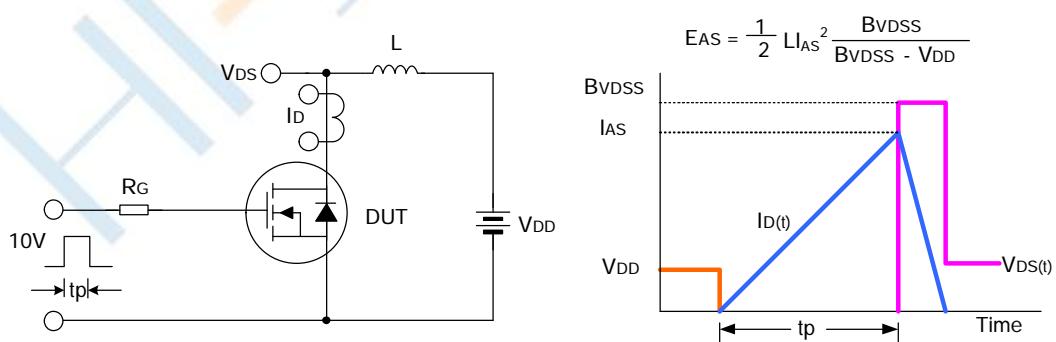
Gate Charge Test Circuit & Waveform



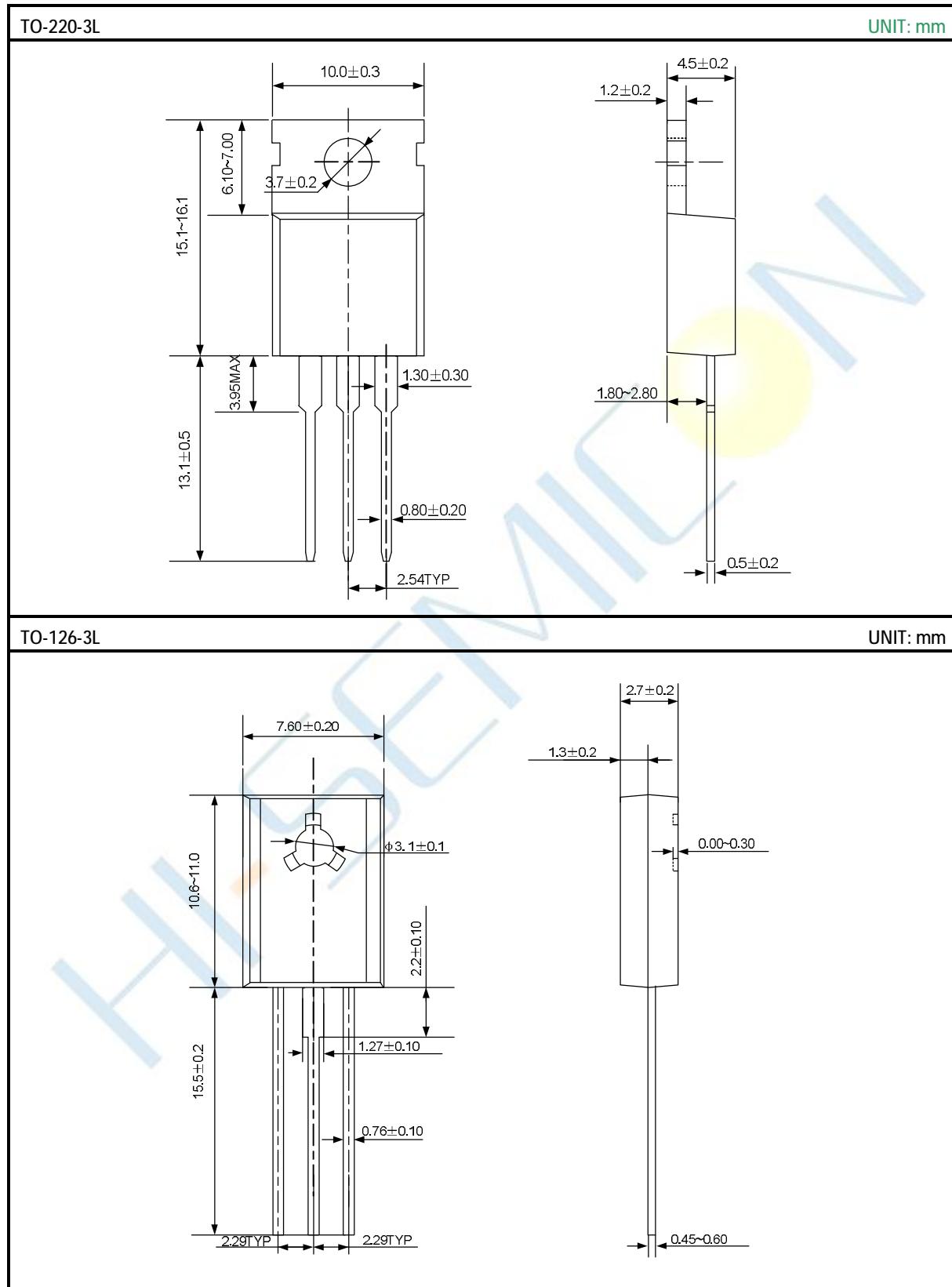
Resistive Switching Test Circuit & Waveform



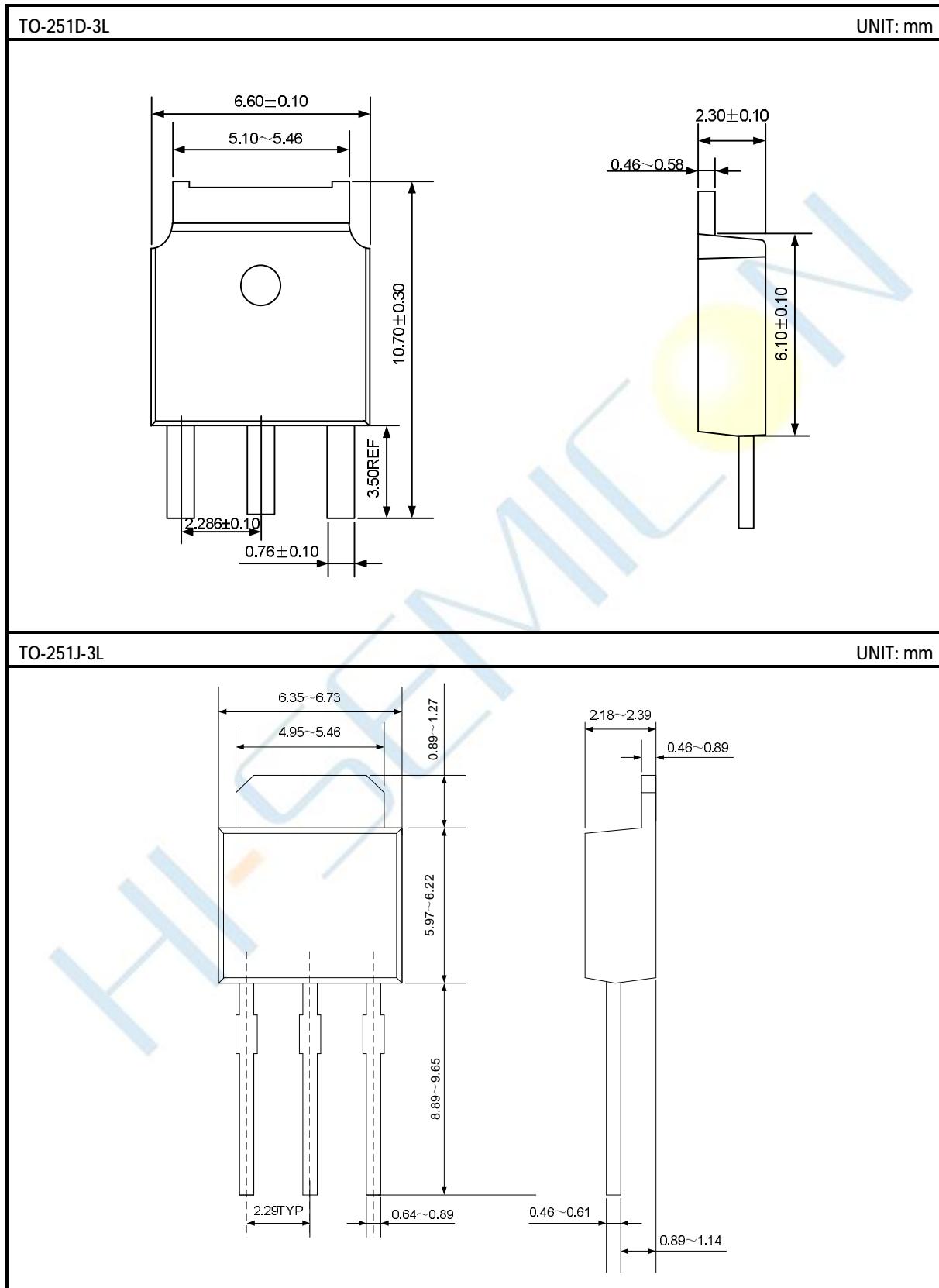
Unclamped Inductive Switching Test Circuit & Waveform



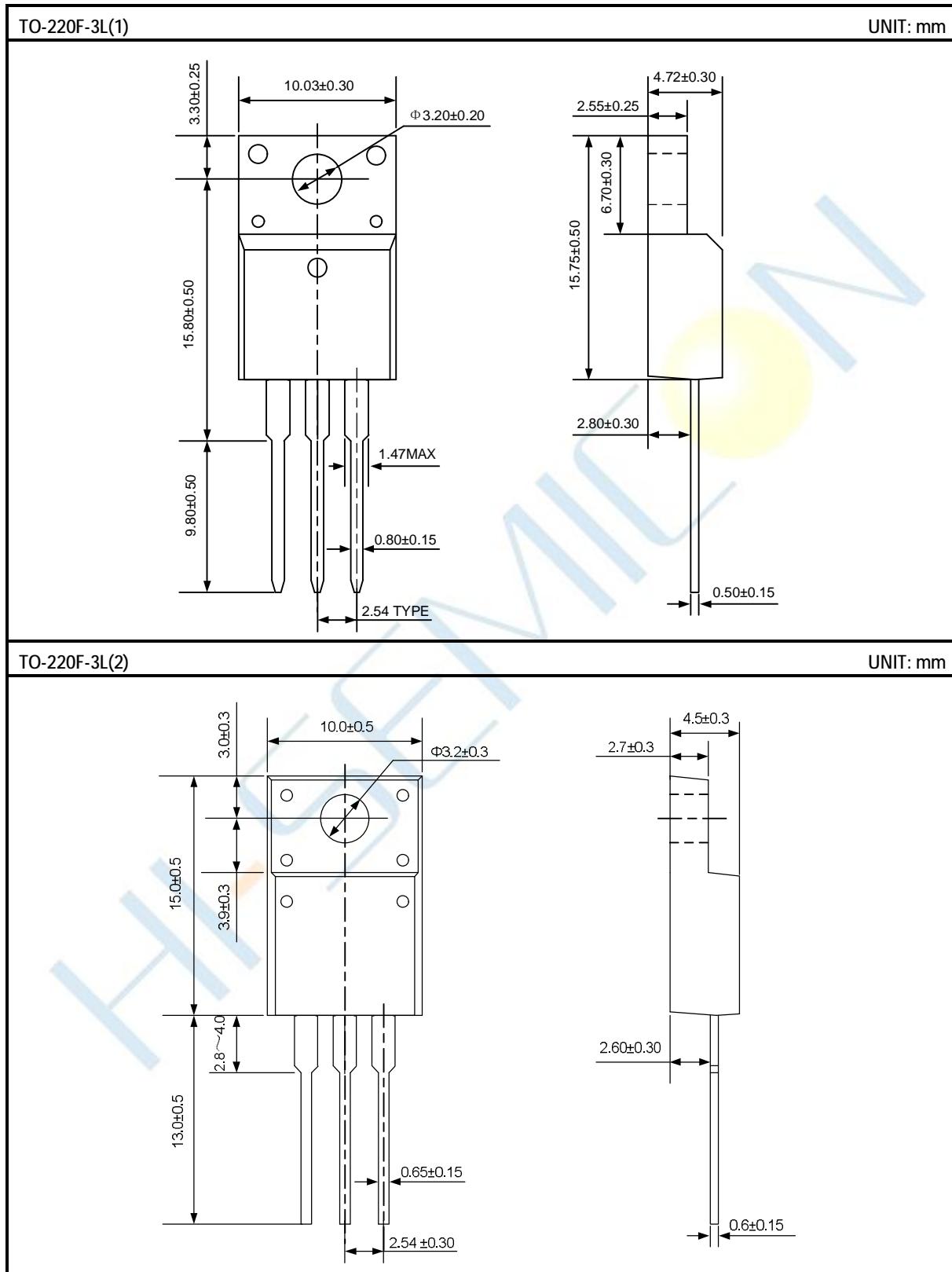
PACKAGE OUTLINE



PACKAGE OUTLINE (continued)



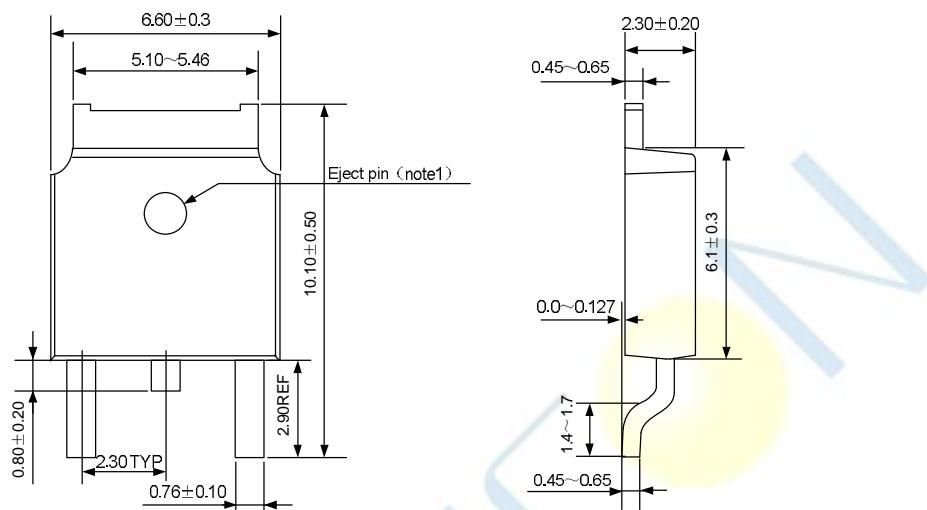
PACKAGE OUTLINE (continued)



PACKAGE OUTLINE (continued)

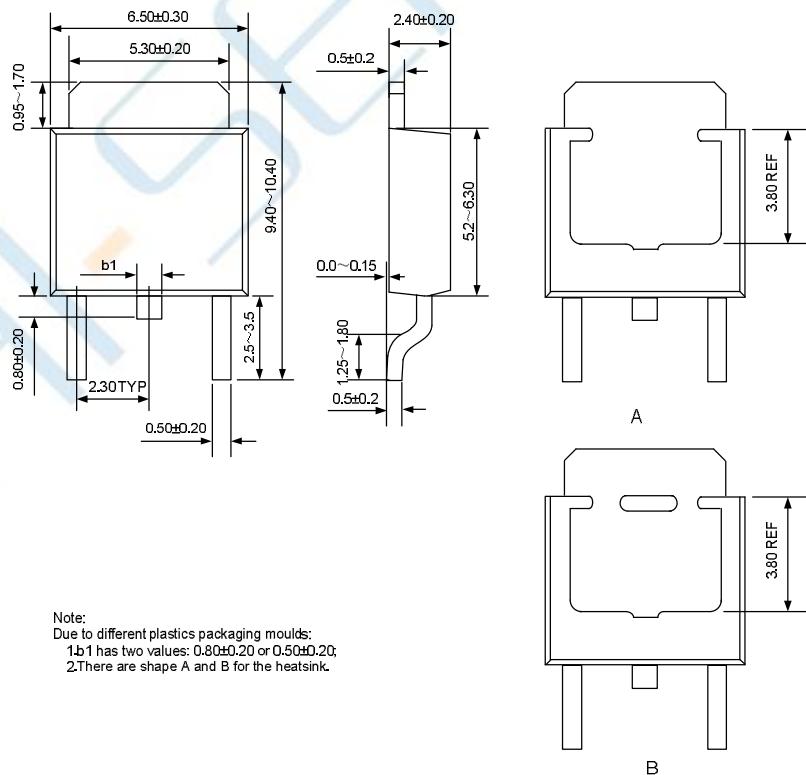
TO-252-2L(1)

UNIT: mm

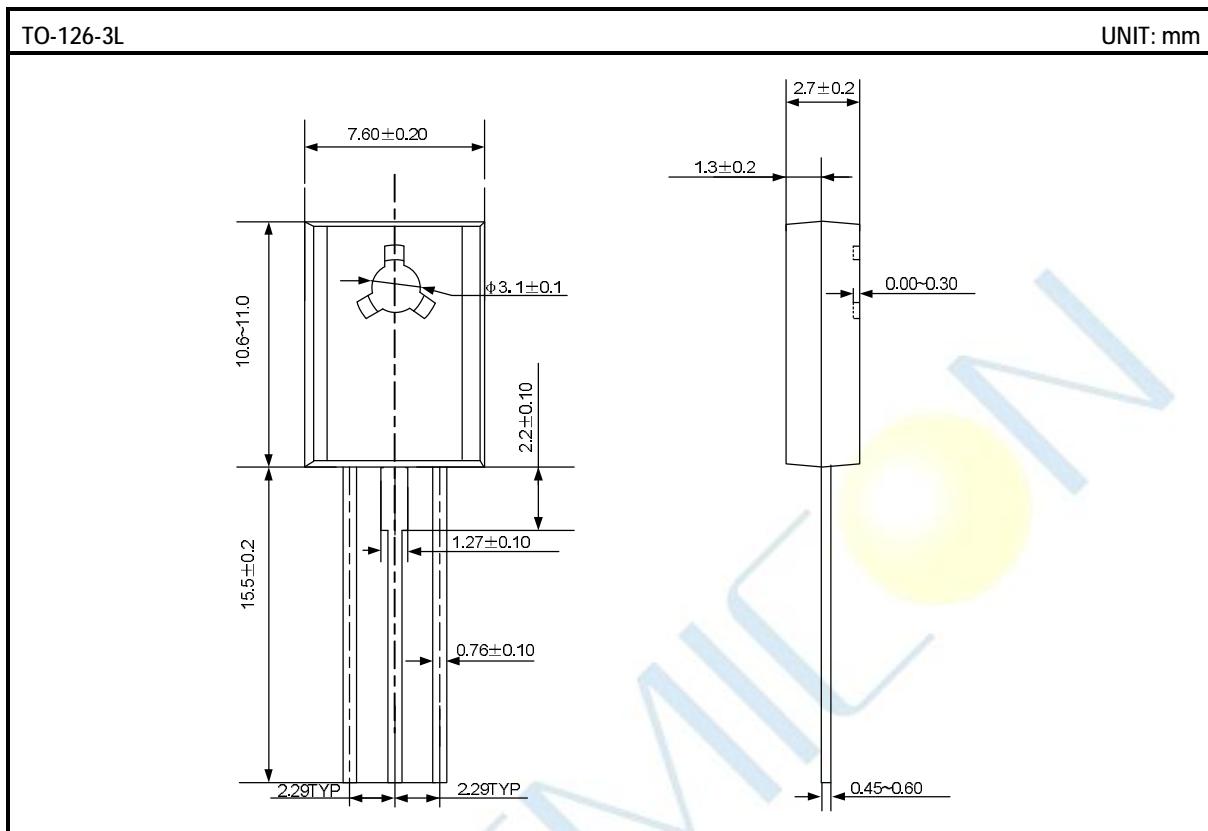


TO-252-2L(2)

UNIT: mm



PACKAGE OUTLINE (continued)



Disclaimer:

- Hi-semicon reserves the right to make changes to the information herein for the improvement of the design and performance without further notice! Customers should obtain the latest relevant information before placing orders and should verify that such information is complete and current.
- All semiconductor products malfunction or fail with some probability under special conditions. When using Hi-semicon products in system design or complete machine manufacturing, it is the responsibility of the buyer to comply with the safety standards strictly and take essential measures to avoid situations in which a malfunction or failure of such Hi-semicon products could cause loss of body injury or damage to property.
- Hi-semicon will supply the best possible product for customers!